Preferred Device

SWITCHMODE™ Power Rectifier

... using the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

- Dual Diode Construction Terminals 1 and 3 may be Connected for Parallel Operation at Full Rating
- Guardring for Stress Protection
- Low Forward Voltage
- 150°C Operating Junction Temperature

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 4.3 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 30 units per plastic tube
- Marking: B3045

MAXIMUM RATINGS

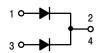
Rating	Symbol	Max	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	rse Voltage V _{RWM}		V
Average Rectified Forward Current (Rated V_R , $T_C = 105^{\circ}C$) Per Device Per Diode		30 15	A
Peak Repetitive Forward Current, (Rated V _R , Square Wave, 20 kHz) Per Diode		30	A
Non–Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	200	A
Peak Repetitive Reverse Current (2.0 μs, 1.0 kHz) Per Diode See Figure 6.	I _{RRM}	2.0	A
Storage Temperature Range	T _{stg}	-65 to +175	°C
Operating Junction Temperature	TJ	-65 to +150	°C
Peak Surge Junction Temperature (Forward Current Applied)	T _{J(pk)}	175	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs

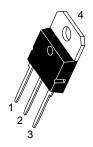


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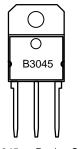
SCHOTTKY BARRIER RECTIFIER 30 AMPERES 45 VOLTS





SOT-93 CASE 340D PLASTIC

MARKING DIAGRAM



B3045 = Device Code

ORDERING INFORMATION

Device	Package	Shipping	
MBR3045PT	SOT-93	30 Units/Rail	

Preferred devices are recommended choices for future use and best overall value.

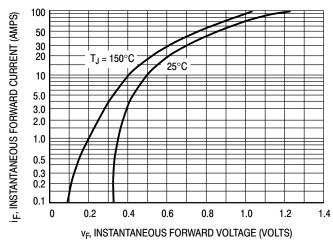
THERMAL CHARACTERISTICS PER DIODE

Rating	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.4	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	40	°C/W

ELECTRICAL CHARACTERISTICS PER DIODE

Instantaneous Forward Voltage (Note 1.) ($i_F = 20 \text{ Amps}$, $T_C = 125^{\circ}\text{C}$) ($i_F = 30 \text{ Amps}$, $T_C = 125^{\circ}\text{C}$) ($i_F = 30 \text{ Amps}$, $T_C = 25^{\circ}\text{C}$)	VF	0.60 0.72 0.76	Volts
Instantaneous Reverse Current (Note 1.) (Rated dc Voltage, $T_C = 125$ °C) (Rated dc Voltage, $T_C = 25$ °C)	İR	100 1.0	mA

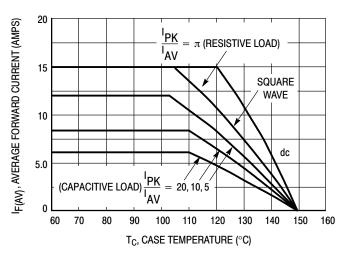
^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.



100 T_J = 150°C 125°C 100°C 125°C 100°C 1

Figure 1. Typical Forward Voltage

Figure 2. Typical Reverse Current



PF(AV), AVERAGE FORWARD POWER DISSIPATION (WATTS) 20 (CAPACITIVE LOAD) I PK I AV SINE WAVE = 20, 10, 5RESISTIVE LOAD 15 SQUARE WAVE 10 $T_J = 125^{\circ}C$ 5.0 5.0 15 25 35 I_{F(AV)}, AVERAGE FORWARD CURRENT (AMPS)

Figure 3. Current Derating (Per Leg)

Figure 4. Forward Power Dissipation (Per Leg)

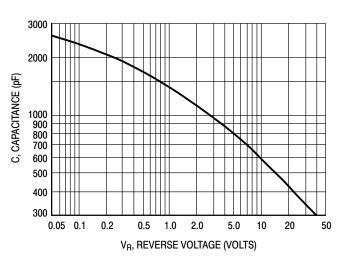


Figure 5. Capacitance

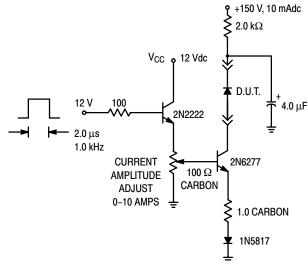
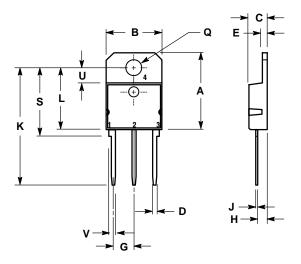


Figure 6. Test Circuit for Repetitive Reverse Current

PACKAGE DIMENSIONS

SOT-93 (TO-218) PLASTIC CASE 340D-02 ISSUE B



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 V14 FM 1092
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α		20.35		0.801
В	14.70	15.20	0.579	0.598
С	4.70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
E	1.17	1.37	0.046	0.054
G	5.40	5.55	0.213	0.219
Н	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L		16.20		0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157 REF	
٧	1.75 REF		0.069	

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